AC6329B Datasheet

Zhuhai Jieli Technology Co.,LTD

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AC6329B Features

High performance 32-bit RISC CPU

- RISC 32-bit CPU
- DC-96MHz operation
- 73KB data RAM
- 8KB I-cache 2way
- 1KB Rocache 1way
- 64 Vectored interrupts
- 8 Levels interrupt priority

Flexible I/O

- 9 GPIO pins
- All GPIO pins can be programmable as input or output individually
- All GPIO pins are internal pull-up/pull-down selectable individually
- CMOS/TTL level schmitt triggered input
- External wake up/interrupt on all GPIOs

Peripheral Feature

- One Full Speed USB OTG controller
- Four Multi-function 32-bit timers, support capture and PWM mode
- Three full-duplex advanced UART(DMA)
- One IIC interface supports host and device mode
- RTC,with alarm clock and time base to wake up the chip
- 16-bit PWM generator for motor driving
- Three IQ Encoder
- 7 channels 10-bit ADC

- 1 channel 8 levels Low Power Detector
- Embedded PMU support low power mode
- 1 Crystal Oscillator
- Watchdog
- Power-on reset

Bluetooth Feature

- CMOS single-chip fully-integrated radio and baseband
- Compliant with Bluetooth
 V5.4+BR+EDR+BLE specification
- Bluetooth Piconet and Scatternet support
- Meet class2 and class3 transmitting power requirement
- Support GFSK and π/4 DQPSK all packet types
- Maximum +8dBm transmitting power
- EDR receiver with -93dBm sensitivity
- Support a2dp\avctp\avdtp\avrcp\hfp\spp\smp\ att\gap\gatt\rfcomm\sdp\l2cap profile

Power Supply

VDDIO is 1.8V to 3.4V

Packages

SOP16

Temperature

- Operating temperature: -40°C to +85°C
- Storage temperature: -65°C to +150°C

1. Block Diagram

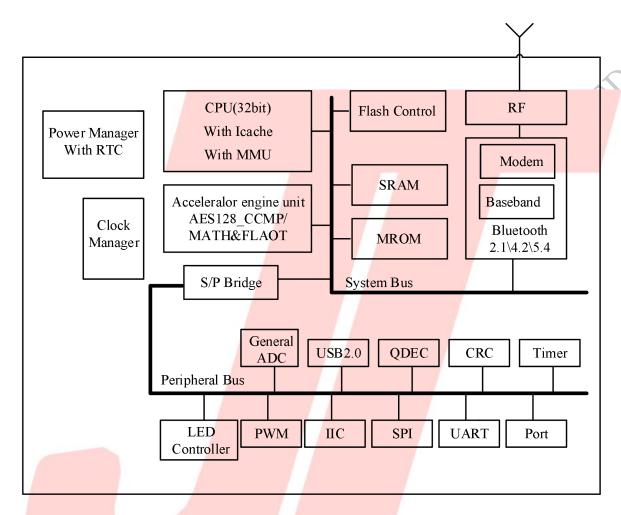


Figure 1-1 AC6329B_SOP16 Block Diagram

2. Pin Definition

2.1 Pin Assignment

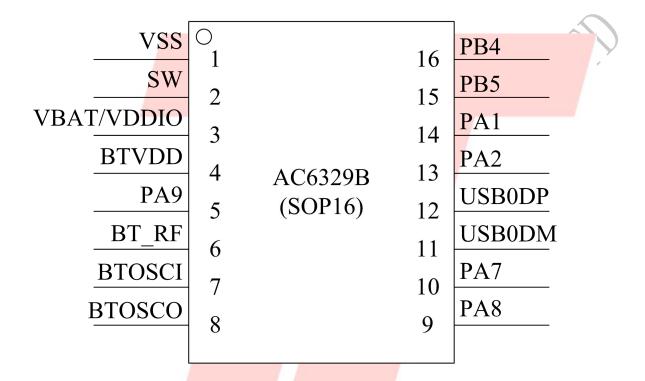


Figure 2-1 AC6329B SOP16 Package Diagram

2.2 Pin Description

Table 2-1 AC6329B_SOP16 Pin Description

PIN NO.	Name	I/O Type	Function	Other Function
1	VSS	P	GND	
2	SW	P	DC-DC Switch Pin	-
	VBAT	P	LDO Power	-
3	VDDIO	P	IO Power 3.3V	-
4	BTAVDD	P	Core Power 1.3V	
5	PA9	I/O	GPIO (pull up)	Long Press Reset; ADC8: ADC Channel 8;
6	BT_RF	-	RF Antenna	- /
7	BTOSCI	I	BTOSCI	- / /
8	BTOSCO	О	BTOSCO	-/
9	PA8	I/O	GPIO	TMR3: Timer3 Clock In; IIC_SDA_C: IIC SDA(C); ADC4: ADC Channel 4; UART1_RXC: Uart1 Data In(C); PWMCH1L;
10	PA7	I/O	GPIO	TMR1: Timer1 Clock In; IIC_SCL_C: IIC SCL(C); ADC3: ADC Channel 3; UART1_TXC: Uart1 Data Out(C); PWMCH1H;
11	USB0DM	I/O	GPIO (pull down)	IIC_SDA_A: IIC SDA(A); ADC11: ADC Channel 11; UART1_RXD: Uart1 Data In(D);
12	USB0DP	I/O	GPIO (pull down)	IIC_SCL_A: IIC SCL(A); ADC10: ADC Channel 10; UART1_TXD: Uart1 Data Out(D);
13	PA2	I/O	GPIO	CAP3: Timer3 Capture; Q-decoder0_1; UART0_RXC: Uart0 Data In(C); UART1_RTS;

				PWM0: Timer0 PWM Output;
				Q-decoder0_0;
14	PA1	I/O	GPIO	ADC0: ADC Channel 0;
				UART0_TXC: Uart0 Data Out(C);
				UART1_CTS;
			CDIO	UART1_RXA: Uart1 Data In(A);
15	PB5	I/O	GPIO	Q-decoder2_1;
		/	(High Voltage)	PWMCH3L;
				TMR2: Timer2 Clock In;
				Q-decoder2_0;
16	PB4	I/O	GPIO	ADC9: ADC Channel 9;
				UAR1_TXA: Uart1 Data Out(A);
				РWМСН3Н;

3. Electrical Characteristics

3.1 Absolute Maximum Ratings

Table 3-1

Symbol	Parameter	Min	Max	Unit
Topt	Operating temperature	-40	+85	°C
Tstg	Storage temperature	-65	+150	°C
VDDIO	3.3V IO Input Voltage	-0.3	3.6	V

Note: The chip can be damaged by any stress in excess of the absolute maximum ratings listed below

3.2 Recommended Operating Conditions

Table 3-2

Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
VDDIO	Voltage input	1.8	3.0	3.4	V	
BTAVDD	Voltage output	1	1.3	1.4	V	DC-DC mode: 40mA loading
I _{VDDIO}	Loading current	-		60	mA	

3.3 IO Input/Output Electrical Logical Characteristics

Table 3-3

Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
V_{IL}	Low-Level Input Voltage	-0.3	-	0.3* VDDIO	V	VDDIO = 3.3V
V_{IH}	High-Leve <mark>l Input</mark> Voltage	0.7* VDDIO	-	VDDIO+0.3	V	VDDIO = 3.3V
IO output	characterist <mark>ics</mark>					
V _{OL}	Low-Level Output Voltage	_	_	0.33	V	VDDIO = 3.3V
V_{OH}	High-Level Output Voltage	2.7	_	7-/	V	VDDIO = 3.3V

3.4 Internal Resistor Characteristics

Table 3-4

Port	Drive Strength	Internal Pull-Up Resistor	Internal Pull-Down Resistor	Comment
PA1-PA9, PB4	drive_select[11] 24mA drive_select[10] 24mA (with 120ohm res) drive_select[01] 8mA drive_select[00] 8mA (with 120ohm res)	10K	10K	1. PA9 default pull up 2. USB0DM&USB0DP default pull down 3. Internal pull-up/pull-down resistance accuracy ±20%
PB5	8mA	10K	10K	5.PB5 can pull-up resistance
USB0DP	4mA	1.5K	15K	to 5V
USB0DM	4mA	180K	15K	

3.5 BT Characteristics

3.5.1 Transmitter

Basic Rate Table 3-5

Paramete	er	Min	Тур	Max	Unit	Test Conditions
RF Transmit I	Power	-	4	6	dBm	
RF Power Contro	ol Range	-	20	-	dB	25°C,
20dB Bandw	ridth	-	950	//-	KHz	Power Supply
In-band spurious	$F=F_0\pm 1MHz$	-	-20	-	dBm	VBAT=3.7V
Emissions	$F=F_0\pm 2MHz$	-	-45	<u> </u>	dBm	2441MHz
(BQB Test Mode	$F=F_0\pm 3MHz$	-	-35	-	dBm	DH5
RF_Tx Power=4dBm)	$F=F_0\pm>3MHz$	-	-40	-	dBm	

Enhanced Data Rate Table 3-6

Paramete	Parameter		Тур	Max	Unit	Test Conditions
Relative Po	wer	-	-1	-	dB	
π/4 DQPSK	DEVM RMS	- "	4	-	%	25°C,
	DEVM 99%	-	12	- 7	%	Power Supply
Modulation Accuracy	DEVM Peak	-/	9	- /	%	
In-band spurious	$F=F_0\pm 1MHz$	7./	-4	4	dBm	VBAT=3.7V
Emissions	$F=F_0\pm 2MHz$	/-/	-30	7-	dBm	2441MHz
(BQB Test Mode	F=F ₀ ±3MHz	7 -	-30	-	dBm	2DH5
RF_Tx Power=4dBm)	$F=F_0\pm>3MHz$	<u> </u>	-37	-	dBm	

3.5.2 Receiver

Basic Rate

Table 3-7

Paramete	r	Min	Тур	Max	Unit	Test Conditions
Sensitivit	y	-	-91	-	dBm	
Co-channel Interferen	Co-channel Interference Rejection		6	-	dB	25°C,
	+1MHz	-	-7	-	dB	Power Supply
	-1MHz	-	-7	-	dB	
Adjacent Channel	+2MHz	-	-37	-	dB	VBAT=3.7V
selectivity C/I	-2MHz	- //	-39		dB	2441MHz
	+3MHz	1	-32	/ /-	dB	DH5
	-3MHz	-	-43	-	dB	

Enhanced Data Rate

Table 3-8

Paramete	er	Min	Тур	Max	Unit	Test Conditions
Sensitivit	y	-	-93	-	dBm	
Co-channel Interferer	Co-channel Interference Rejection		8	-	dB	25°C,
	+1MHz	-	-14	-	dB	Power Supply
	-1MHz	-	-15	-	dB	11.5
Adjacent Channel	+2MHz	- /	-36	-	dB	VBAT=3.7V
selectivity C/I	-2MHz	- 1/	-39	- /	dB	2441MHz
	+3MHz	-///	-29	-/	dB	2DH5
	-3MHz	7- /	-43	-	dB	

3.5.3 BLE

1M Data Rate

Table 3-9

11vi Data Kate	1401	C 3-7				
Paramete	er	Min	Тур	Max	Unit	Test Conditions
Sensitivit	y	-	-95	-	dBm	
RF Transmit F	Power	-	6.5	8	dBm	
In-band Spurious	M-N =2MHz	-	-35	-	dBm	
Emission	M-N ≥3MHz	-	-33	-	dBm	25°C
	Δf1 avg	-	250	-	KHz	Power Supply
Modulation Characteristics	Δf2 99%	-7	210		KHz	VBAT=3.7V
Characteristics	Δflavg/Δf2avg	-	0.9	-	/	2440MHz
Carrier Frequency Offset		-15	- /	+15	KHz	
Frequency Drift		-25	- /	+25	KHz	
Frequency Drift	ft Rate	-5	-/ //	+5	KHz/50us	

2M Data Rate

Table 3-10

Paramete	Parameter		Тур	Max	Unit	Test Conditions
Sensitivity		-	-92	-	dBm	
RF Transmit F	ower	-	6.5	8	dBm	
	M-N =4MHz	-	-40	- /	dBm	
In-band Spurious Emission	M-N =5MHz	-	-40	- /	dBm	25°C
Elinission	M-N ≥6MHz	-///	-40	-	dBm	Power Supply
	Δfl avg	- /- /-	500	/-	KHz	
Modulation Characteristics	Δf2 99%	/-/	430	-	KHz	VBAT=3.7V
Characteristics	Δflavg/Δf2avg	1 1	0.9	-	/	2440MHz
Carrier Frequency Offset		-20	-	+20	KHz	
Frequency Drift		-25	-	+25	KHz	
Frequency Drift	ft Rate	-5	-	+5	KHz/50us	

Long Range

Table 3-11

Parameter	Min	Тур	Max	Unit	Test Conditions
Sensitivity LE 125K(S8)	-	-102	-	dBm	VBAT=3.7V,25°C
Sensitivity LE 500K(S2)	-	-99	-	dBm	2440MHz

4. Package Information

4.1 SOP16(9.9mm*6mm)

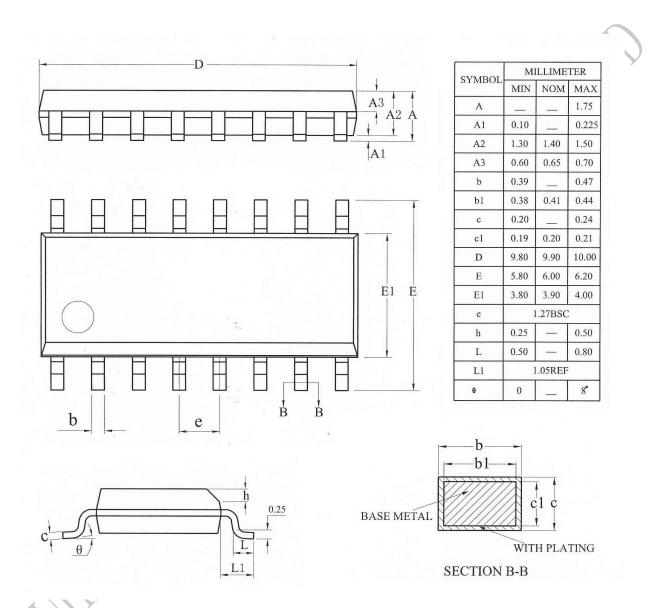


Figure 4-1 AC6329B_SOP16 Package

5. Package Type Specification



- ①Represents different packages
- $@ Represents \ different \ memory \ sizes$
 - 2: 2Mbit Flash

6. Revision History

Date	Revision	Description
2021.03.12	V1.0	Initial Release
2022.07.19	V1.1	Update Bluetooth Feature
2023.11.28	V1.2	Add BLE parameter
2023.12.13	V1.3	Update Bluetooth Feature